



Vishay Siliconix

Low-Voltage Single Asymmetrical SPDT Analog Switch

DESCRIPTION

The DG2020 is a single-pole/double-throw monolithic CMOS analog switch designed for high performance switching of analog signals. Combining low power, high speed, low on-resistance and small physical size, the DG2020 is ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG2020 is built on Vishay Siliconix's low voltage JI2 process. An epitaxial layer prevents latchup. Break-before-make is guaranteed.

The switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

FEATURES

- Low voltage operation (2.7 V to 5.5 V)
- Low on-resistance RON
 - $-NO = 0.8 \Omega$
 - NC = 1.2 Ω
- Low power consumption
- TTL/CMOS compatible
- TSOP-6 package

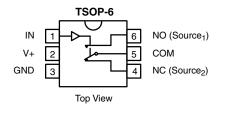
BENEFITS

- Reduced power consumption
- Simple logic interface
- High accuracy
- Reduce board space

APPLICATIONS

- Cellular phones
- Communication systems
- Portable test equipment
- · Battery operated systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Device Marking: E3xxx

TRUTH TABLE					
LOGIC	NC	NO			
0	ON	OFF			
1	OFF	ON			

ORDERING INFORMATION					
TEMP. RANGE	PACKAGE	PART NUMBER			
- 40 °C to 85 °C	TSOP-6	DG2020DV			

ABSOLUTE MAXIMUM RATINGS					
PARAMETERS	CONDITIONS	LIMITS	UNIT		
V+	Reference to GND	- 0.3 to 6	V		
IN, COM, NC, NO ^a	Reference to GND	- 0.3 to (V+ + 0.3 V)	v		
Continuous Current (any terminal)	Reference to GND	± 50			
Peak Current (pulsed at 1 ms, 10 % duty cycle)	Reference to GND	± 200	mA		
Storage Temperature (D suffix)	Reference to GND	- 65 to + 125	°C		
TSOP-6°	Power Dissipation (packages) ^b	570	mW		

Notes

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 7 mW/C above 25 °C.



DG2020

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SPECIFICATION (V+ = 3 V)							
	TEST CONDITION			LIMITS (- 40 °C TO 85 °C)			
PARAMETER	SYMBOL	UNLESS OTHERWISE SPECIFIED, V+ = 3 V, \pm 10 %, V _{IN} = 0.4 V or 2 V ^e	TEMP. ^a	MIN. ^b	TYP.℃	MAX. ^b	UNIT
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0	-	V+	V
	P		Room	-	1.4	2	
On-Resistance	R _{ON(NO)}	V+ = 2.7 V,	Full	-	1.5	2.1	Ω
OII-Resistance	D	$V_{COM} = 1.5 \text{ V}, I_{NO}, I_{NC} = 100 \text{ mA}$	Room	-	2.2	3.2	
	R _{ON(NC)}		Full	-	2.3	3.3	22
R _{ON} Flatness ^d	R _{ON(NO)} Flatness	$V_{\rm H} = 2.7 \ V, \ V_{\rm COM} = 0 \ V \ to \ V_{\rm +}, \ I_{\rm NO}, \ I_{\rm NC} = 100 \ mA$	Room	-	0.42	-	
	have been		Room	- 2.3	-	2.3	
Switch Off	I _{NO(off)} , I _{NC(off)}	V+ = 3.3 V,	Full	- 60	-	60	
Leakage Current ^f	laave ee	V_{NO} , V_{NC} = 1 V/3 V, V_{COM} = 3 V/1 V	Room	- 2.3	-	2.3	nA
	I _{COM} (off)		Full	- 60	-	60	
Channel-On	1	V+ = 3.3 V,	Room	- 2.3	-	2.3	
Leakage Current ^f	ICOM(on)	V_{NO} , $V_{NC} = V_{COM} = 1 \text{ V/3 V}$	Full	- 60	-	60	
Digital Control							
Input High Voltage	V _{INH}		Full	2	-	-	V
Input Low Voltage	V _{INL}		Full	-	-	0.4	v
Input Capacitance	C _{IN}		Full	-	3.7	-	pF
Input Current	I _{NL} or I _{NH}	V _{IN} = 0 or V+	Full	1	-	1	μA
Dynamic Characteristics	5						
	+		Room	-	6	10	μs
Turn-On Time	t _{ON(NO)}		Full	-	-	11	
Turn-On Time			Room	-	5	7	
	t _{ON(NC)}	V_{NO} or $V_{NC} = 2 V$,	Full	-	-	8	
		$R_L = 300 \Omega$, $C_L = 35 pF$	Room	-	2	5	
Turne Off Times	t _{OFF(NO)}		Full	-	-	5.5	
Turn-Off Time			Room	-	2	4	
	t _{OFF(NC)}		Full	-	-	4.5	
Break-Before-Make Time	t _d	V_{NO} or V_{NC} = 2 V, R_L = 300 Ω , C_L = 35 pF	Full	1	3	-	
Charge Injection ^d	Q _{INJ}	$C_L = 1 \text{ nF}, V_{GEN} = 0 \text{ V}, R_{GEN} = 0 \Omega$	Room	-	1	-	рС
Off-Isolation ^d	QIRR		Room	-	- 52	-	- ID
Crosstalk ^d	X _{TALK}	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$	Room	-	- 53	-	dB
NO, NC Off	t _{ON(NO)}		Room	-	75	-	
Capacitanced	t _{ON(NC)}		Room	-	34	-	рF
Channel-On	t _{OFF(NO)}	$V_{IN} = 0$ or V+, f = 1 MHz	Room	-	88	-	
Capacitance ^d	t _{OFF(NC)}		Room	-	95	-	
Power Supply		·					
Power Supply Range	V+		-	2.7	-	3.3	V
Power Supply Current	l+		Full	-	0.2	1	μA
Power Consumption	Pc	V _{IN} = 0 or V+	Full	-	-	3.3	μW

Notes

a. Room = 25 °C, Full = as determined by the operating suffix.

b. Typical values are for design aid only, not guaranteed nor subject to production testing.

c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.

d. Guarantee by design, nor subjected to production test.

e. V_{IN} = input voltage to perform proper function.

f. Guaranteed by 5 V leakage testing, not production tested.

2



DG2020

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SPECIFICATION (V+ = 5 V)							
		TEST CONDITION		LIMITS (- 40 °C TO 85 °C)			
PARAMETER	SYMBOL	UNLESS OTHERWISE SPECIFIED, V+ = 5 V, \pm 10 %, V _{IN} = 0.8 V or 2.4 V ^e	TEMP. ^a	MIN. ^b	TYP.℃	MAX. ^b	UNIT
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0	-	V+	V
	Baurua		Room	-	0.8	1.1	
On-Resistance	R _{ON(NO)}	V+ = 4.5 V,	Full	-	0.9	1.2	Ω
On-nesistance	P	$V_{COM} = 3 \text{ V}, \text{ I}_{NO}, \text{ I}_{NC} = 100 \text{ mA}$	Room	-	1.2	1.6	
	R _{ON(NC)}		Full	-	1.3	1.7	
R _{ON} Flatness ^d	R _{ON(NO)} Flatness	$V+=4.5 \text{ V}, \\ V_{COM}=0 \text{ V to } V+\text{, } I_{NO}\text{, } I_{NC}=100 \text{ mA}$	Room	-	0.13	-	
			Room	- 5.3	-	5.3	
Switch Off	I _{NO(off)} , I _{NC(off)}	V+ = 5.5 V,	Full	- 98	-	98	
Leakage Current	0004/55	V_{NO} , V_{NC} = 1 V/4.5 V, V_{COM} = 4.5 V/1 V	Room	- 5.3	-	5.3	nA
	I _{COM} (off)		Full	- 98	-	98	
Channel-On	lease s	V+ = 5.5 V,	Room	- 5.3	-	5.3	
Leakage Current	I _{COM(on)}	V_{NO} , $V_{NC} = V_{COM} = 1 \text{ V/4.5 V}$	Full	- 98	-	98	
Digital Control							
Input High Voltage	V _{INH}		Full	2.4	-	-	v
Input Low Voltage	V _{INL}		Full	-	-	0.8	v
Input Capacitance	C _{IN}		Full	-	3.5	-	pF
Input Current	I_{NL} or I_{NH}	V _{IN} = 0 or V+	Full	1	-	1	μA
Dynamic Characteristics	;						
	t _{ON(NO)}		Room	-	3	6	μs
Turn-On Time			Full	-	-	6.5	
	t _{ON(NC)}		Room	-	2	5	
		V_{NO} or $V_{NC} = 3 V$,	Full	-	-	5.5	
	t _{OFF(NO)} t _{OFF(NC)}	$R_L = 300 \Omega$, $C_L = 35 pF$	Room	-	1	4	
Turn-Off Time			Full	-	-	4.5	
Tum-On Time			Room	-	1	3	
			Full	-	-	3.5	
Break-Before-Make Time	t _d	$V_{NO} \text{ or } V_{NC} = 3 \text{ V}, \text{ R}_{L} = 300 \Omega, \text{ C}_{L} = 35 \text{ pF}$	Full	0.3	1.5	-	
Charge Injection ^d	Q _{INJ}	C_L = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 Ω	Room	-	5	-	рС
Off-Isolation ^d	QIRR		Room	-	- 53	-	٩D
Crosstalk ^d	X _{TALK}	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$	Room	-	- 54	-	dB
NO, NC Off	t _{ON(NO)}		Room	-	65	-	
Capacitanced	t _{ON(NC)}		Room	-	32	-	- 5
Channel-On	t _{OFF(NO)}	$V_{IN} = 0$ or V+, f = 1 MHz	Room	-	90	-	pF
Capacitance ^d	t _{OFF(NC)}		Room	-	95	-	
Power Supply							
Power Supply Range	V+			4.5	-	5.5	V
Power Supply Current	l+		Full	-	0.2	1	μA
Power Consumption	Pc	V _{IN} = 0 or V+	Full	-	-	5.5	μW

Notes

a. Room = 25 °C, Full = as determined by the operating suffix.

b. Typical values are for design aid only, not guaranteed nor subject to production testing.

c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.

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e. V_{IN} = input voltage to perform proper function.

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3

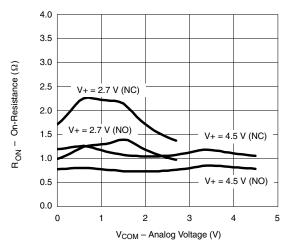
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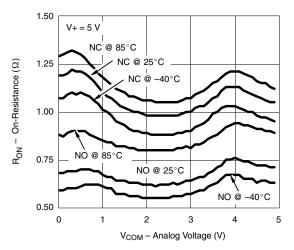


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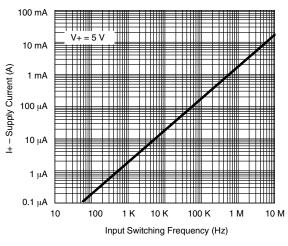
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



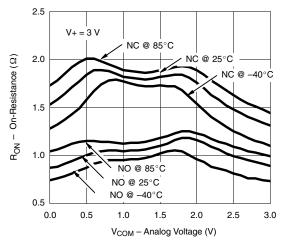
R_{ON} vs. V_{COM} and Supply Voltage



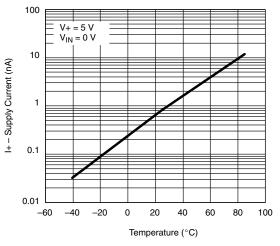
R_{ON} vs. Analog Voltage and Temperature



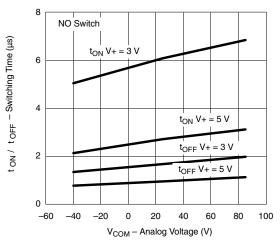
Supply Current vs. Input Switching Frequency



R_{ON} vs. Analog Voltage and Temperature



Supply Current vs. Temperature



Switching Time vs. Temperature and Supply Voltage

S13-1633-Rev. B, 22-Jul-13

4

Document Number: 71676

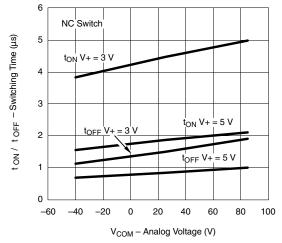
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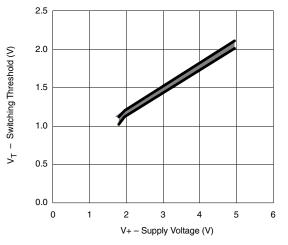
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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)

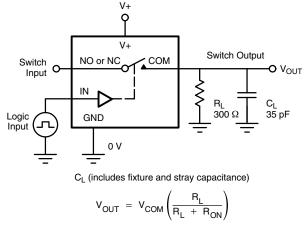


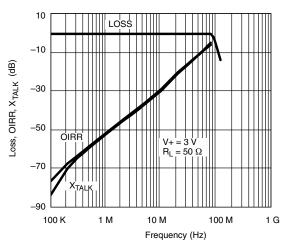
Switching Time vs. Temperature and Supply Voltage



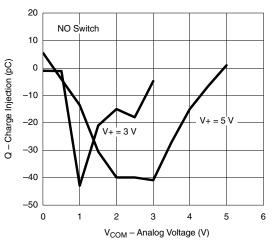
Switching Threshold vs. Supply Voltage

TEST CIRCUITS

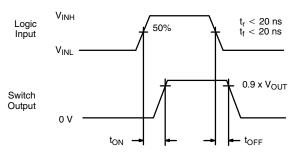




Insertion Loss, Off-Isolation Crosstalk vs. Frequency



Charge Injection vs. Analog Voltage



Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

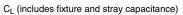
Fig. 1 - Switching Time

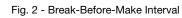
S13-1633-Rev. B, 22-Jul-13

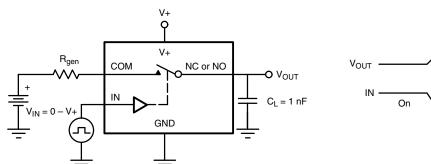
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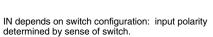
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Off

 $Q = \Delta V_{OUT} \times C_L$

ΔV_{OUT}



V+ Q 10 nF V+ NC or NO 0V, 2.4 V IN СОМ -0 СОМ R GND Analyzer V_{COM} Off Isolation = $20 \log \frac{1}{V_{NO/NC}}$ -

Fig. 4 - Off-Isolation

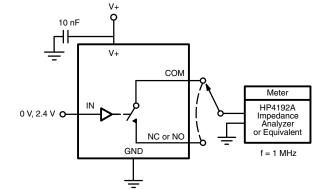


Fig. 5 - Channel off/on Capacitance

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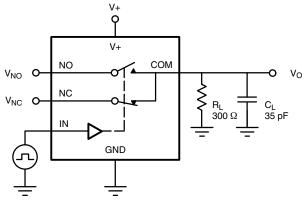


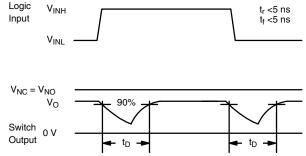
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On

TEST CIRCUITS

Vgen





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Package Information

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TSOP: 5/6-LEAD JEDEC Part Number: MO-193C









6-LEAD TSOP



	MILLIMETERS			I	NCHES	
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.91	-	1.10	0.036	-	0.043
A ₁	0.01	-	0.10	0.0004	-	0.004
A ₂	0.90	-	1.00	0.035	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
С	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
Е	2.70	2.85	2.98	0.106	0.112	0.117
E ₁	1.55	1.65	1.70	0.061	0.065	0.067
е	0.95 BSC			(0.0374 BSC	;
e ₁	1.80	1.90	2.00	0.071 0.075 0.07		0.079
L	0.32	-	0.50	0.012	-	0.020
L ₁		0.60 Ref			0.024 Ref	
L ₂	0.25 BSC				0.010 BSC	
R	0.10	-	-	0.004	-	-
θ	0°	4°	8°	0°	4°	8°
θ_1	7° Nom				7° Nom	
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540						

PAD Pattern



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Recommended Land Pattern For TSOP-5L / TSOP-6L





TSOP 5L





Note

• All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022	
DWG: 3010	

1



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Revision: 01-Jan-2025

1